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Applications of "[Embedded - Microcontrollers](#)"

Details

Product Status	Not For New Designs
Core Processor	M16C/60
Core Size	16-Bit
Speed	32MHz
Connectivity	EBI/EMI, I ² C, SIO, UART/USART
Peripherals	DMA, LVD, POR, PWM, WDT
Number of I/O	111
Program Memory Size	384KB (384K x 8)
Program Memory Type	FLASH
EEPROM Size	-
RAM Size	31K x 8
Voltage - Supply (Vcc/Vdd)	2.7V ~ 5.5V
Data Converters	A/D 26x10b; D/A 2x8b
Oscillator Type	Internal
Operating Temperature	-40°C ~ 85°C (TA)
Mounting Type	Surface Mount
Package / Case	128-LQFP
Supplier Device Package	128-LFQFP (14x20)
Purchase URL	https://www.e-xfl.com/product-detail/renesas-electronics-america/r5f3651kdfc-u0

1.5 Pin Assignments

Figure 1.5 to Figure 1.7 show pin assignments. Table 1.7 to Table 1.11 list pin names.

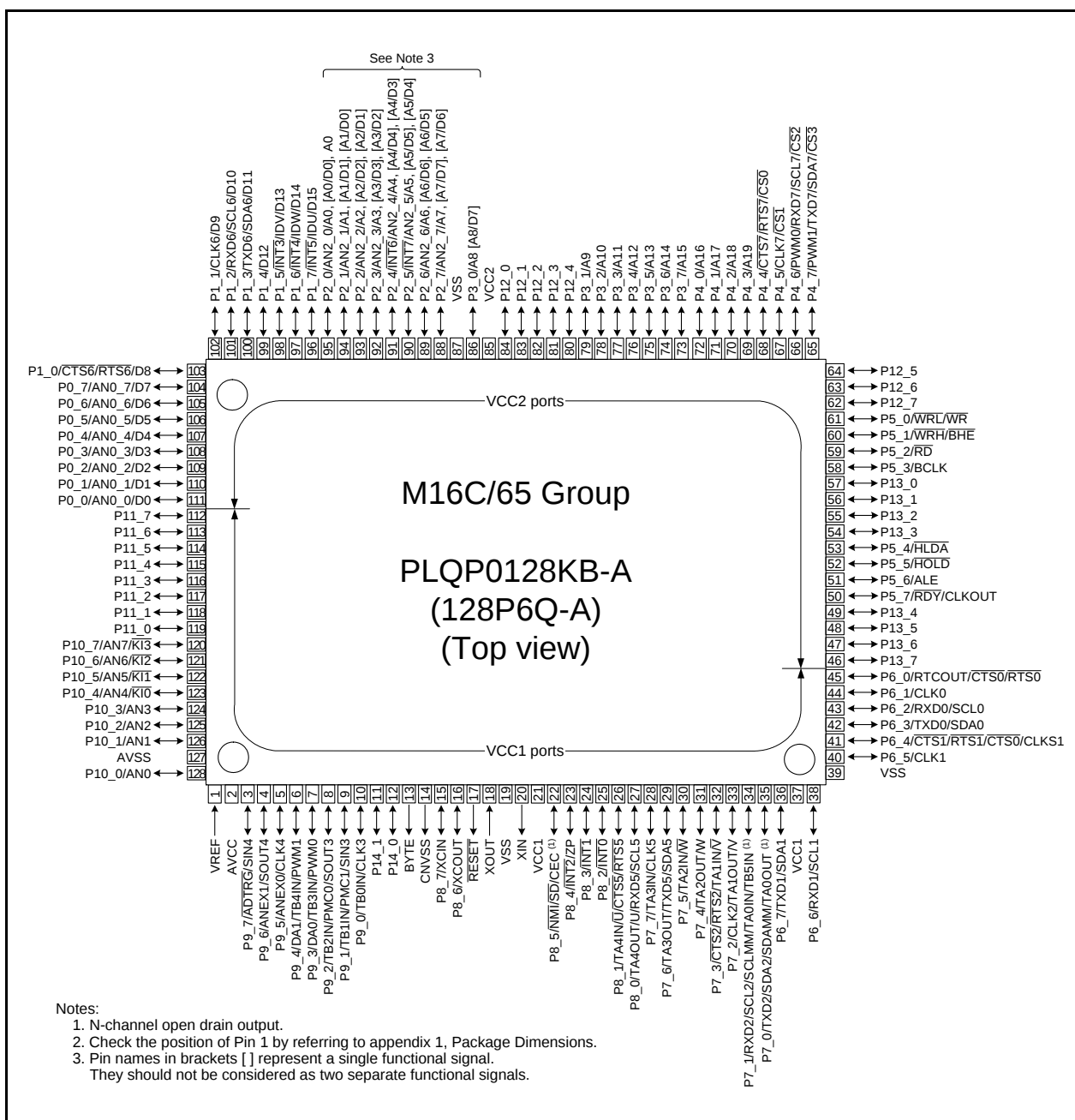


Figure 1.5 Pin Assignment for the 128-Pin Package

3. Address Space

3.1 Address Space

The M16C/65 Group has a 1 MB address space from 00000h to FFFFFh. Address space is expandable to 4 MB with the memory area expansion function. Addresses 40000h to BFFFFh can be used as external areas from bank 0 to bank 7. Figure 3.1 shows the Address Space. Areas that can be accessed vary depending on processor mode and the status of each control bit.

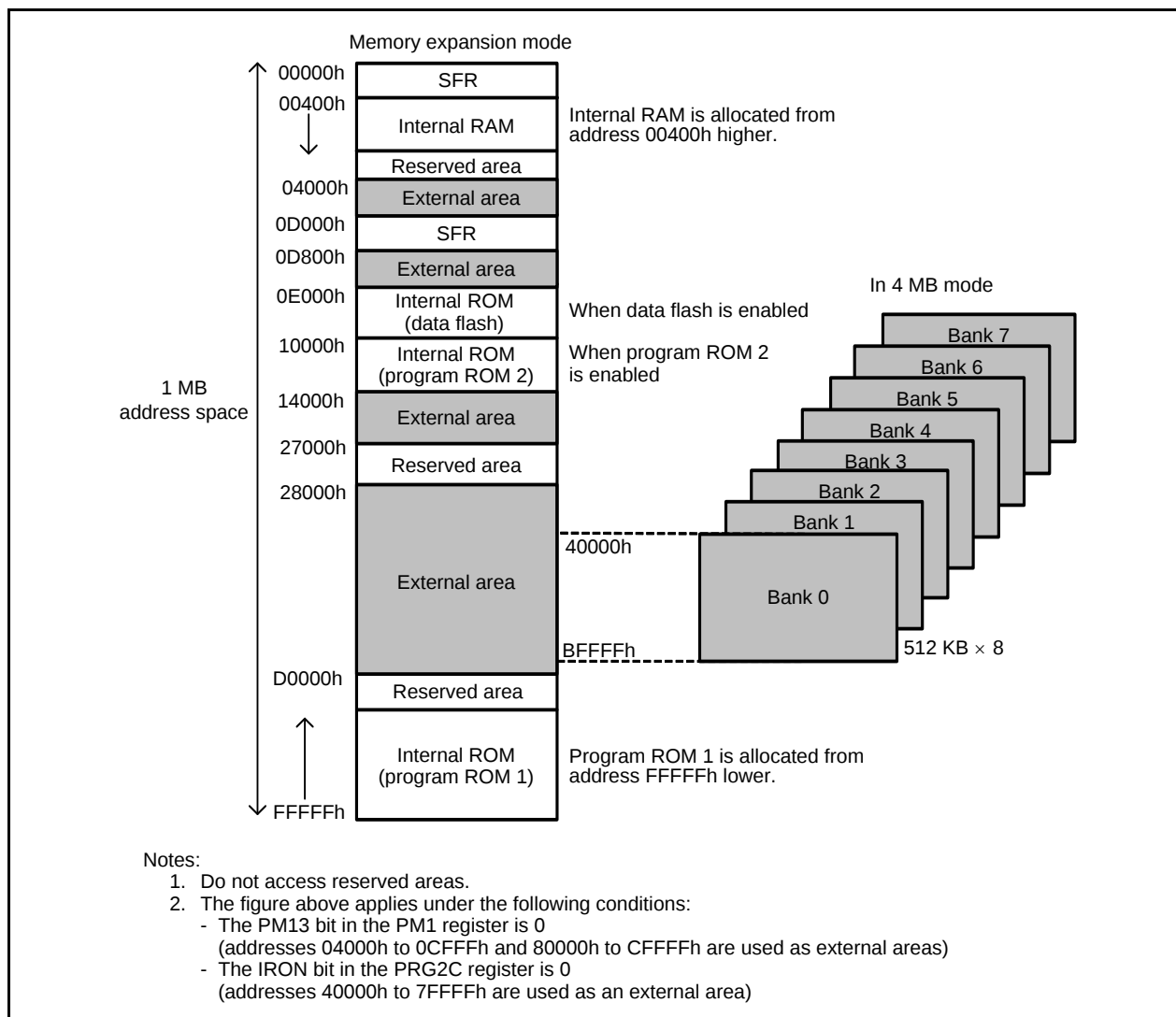


Figure 3.1 Address Space

Table 4.3 SFR Information (3) ⁽¹⁾

Address	Register	Symbol	Reset Value
0040h			
0041h			
0042h	INT7 Interrupt Control Register	INT7IC	XX00 X000b
0043h	INT6 Interrupt Control Register	INT6IC	XX00 X000b
0044h	INT3 Interrupt Control Register	INT3IC	XX00 X000b
0045h	Timer B5 Interrupt Control Register	TB5IC	XXXX X000b
0046h	Timer B4 Interrupt Control Register UART1 Bus Collision Detection Interrupt Control Register	TB4IC U1BCNIC	XXXX X000b
0047h	Timer B3 Interrupt Control Register UART0 Bus Collision Detection Interrupt Control Register	TB3IC U0BCNIC	XXXX X000b
0048h	SI/O4 Interrupt Control Register INT5 Interrupt Control Register	S4IC INT5IC	XX00 X000b
0049h	SI/O3 Interrupt Control Register INT4 Interrupt Control Register	S3IC INT4IC	XX00 X000b
004Ah	UART2 Bus Collision Detection Interrupt Control Register	BCNIC	XXXX X000b
004Bh	DMA0 Interrupt Control Register	DM0IC	XXXX X000b
004Ch	DMA1 Interrupt Control Register	DM1IC	XXXX X000b
004Dh	Key Input Interrupt Control Register	KUPIC	XXXX X000b
004Eh	A/D Conversion Interrupt Control Register	ADIC	XXXX X000b
004Fh	UART2 Transmit Interrupt Control Register	S2TIC	XXXX X000b
0050h	UART2 Receive Interrupt Control Register	S2RIC	XXXX X000b
0051h	UART0 Transmit Interrupt Control Register	S0TIC	XXXX X000b
0052h	UART0 Receive Interrupt Control Register	S0RIC	XXXX X000b
0053h	UART1 Transmit Interrupt Control Register	S1TIC	XXXX X000b
0054h	UART1 Receive Interrupt Control Register	S1RIC	XXXX X000b
0055h	Timer A0 Interrupt Control Register	TA0IC	XXXX X000b
0056h	Timer A1 Interrupt Control Register	TA1IC	XXXX X000b
0057h	Timer A2 Interrupt Control Register	TA2IC	XXXX X000b
0058h	Timer A3 Interrupt Control Register	TA3IC	XXXX X000b
0059h	Timer A4 Interrupt Control Register	TA4IC	XXXX X000b
005Ah	Timer B0 Interrupt Control Register	TB0IC	XXXX X000b
005Bh	Timer B1 Interrupt Control Register	TB1IC	XXXX X000b
005Ch	Timer B2 Interrupt Control Register	TB2IC	XXXX X000b
005Dh	INT0 Interrupt Control Register	INT0IC	XX00 X000b
005Eh	INT1 Interrupt Control Register	INT1IC	XX00 X000b
005Fh	INT2 Interrupt Control Register	INT2IC	XX00 X000b

X: Undefined

Note:

1. The blank areas are reserved. No access is allowed.

Table 4.7 SFR Information (7) ⁽¹⁾

Address	Register	Symbol	Reset Value
01E0h	Timer B3-1 Register	TB31	XXh
01E1h			XXh
01E2h	Timer B4-1 Register	TB41	XXh
01E3h			XXh
01E4h	Timer B5-1 Register	TB51	XXh
01E5h			XXh
01E6h	Pulse Period/Pulse Width Measurement Mode Function Select Register 2	PPWFS2	XXXX X000b
01E7h			
01E8h	Timer B Count Source Select Register 2	TBCS2	00h
01E9h	Timer B Count Source Select Register 3	TBCS3	X0h
01EAh			
01EBh			
01ECh			
01EDh			
01EEh			
01EFh			
01F0h	PMC0 Function Select Register 0	PMC0CON0	00h
01F1h	PMC0 Function Select Register 1	PMC0CON1	00XX 0000b
01F2h	PMC0 Function Select Register 2	PMC0CON2	0000 00X0b
01F3h	PMC0 Function Select Register 3	PMC0CON3	00h
01F4h	PMC0 Status Register	PMC0STS	00h
01F5h	PMC0 Interrupt Source Select Register	PMC0INT	00h
01F6h	PMC0 Compare Control Register	PMC0CPC	XXX0 X000b
01F7h	PMC0 Compare Data Register	PMC0CPD	00h
01F8h	PMC1 Function Select Register 0	PMC1CON0	XXX0 X000b
01F9h	PMC1 Function Select Register 1	PMC1CON1	XXXX 0X00b
01FAh	PMC1 Function Select Register 2	PMC1CON2	0000 00X0b
01FBh	PMC1 Function Select Register 3	PMC1CON3	00h
01FCh	PMC1 Status Register	PMC1STS	X000 X00Xb
01FDh	PMC1 Interrupt Source Select Register	PMC1INT	X000 X00Xb
01FEh			
01FFh			
0200h			
0201h			
0202h			
0203h			
0204h			
0205h	Interrupt Source Select Register 3	IFSR3A	00h
0206h	Interrupt Source Select Register 2	IFSR2A	00h
0207h	Interrupt Source Select Register	IFSR	00h
0208h			
0209h			
020Ah			
020Bh			
020Ch			
020Dh			
020Eh	Address Match Interrupt Enable Register	AIER	XXXX XX00b
020Fh	Address Match Interrupt Enable Register 2	AIER2	XXXX XX00b

X: Undefined

Note:

1. The blank areas are reserved. No access is allowed.

Table 4.15 SFR Information (15) ⁽¹⁾

Address	Register	Symbol	Reset Value
0390h	DMA2 Source Select Register	DM2SL	00h
0391h			
0392h	DMA3 Source Select Register	DM3SL	00h
0393h			
0394h			
0395h			
0396h			
0397h			
0398h	DMA0 Source Select Register	DM0SL	00h
0399h			
039Ah	DMA1 Source Select Register	DM1SL	00h
039Bh			
039Ch			
039Dh			
039Eh			
039Fh			
03A0h			
03A1h			
03A2h	Open-Circuit Detection Assist Function Register	AINRST	XX00 XXXXb
03A3h			
03A4h			
03A5h			
03A6h			
03A7h			
03A8h			
03A9h			
03AAh			
03ABh			
03ACh			
03ADh			
03AEh			
03AFh			
03B0h			
03B1h			
03B2h			
03B3h			
03B4h	SFR Snoop Address Register	CRCSAR	XXXX XXXXb
03B5h			00XX XXXXb
03B6h	CRC Mode Register	CRCMR	0XXX XXX0b
03B7h			
03B8h			
03B9h			
03BAh			
03BBh			
03BCh	CRC Data Register	CRCD	XXh
03BDh			XXh
03BEh	CRC Input Register	CRCIN	XXh
03BFh			

X: Undefined

Note:

1. The blank areas are reserved. No access is allowed.

Table 5.3 Recommended Operating Conditions (2/3)

$V_{CC1} = V_{CC2} = 2.7$ to 5.5 V at $T_{opr} = -20^{\circ}\text{C}$ to $85^{\circ}\text{C}/-40^{\circ}\text{C}$ to 85°C unless otherwise specified.

Symbol	Parameter		Standard			Unit
			Min.	Typ.	Max.	
$I_{OL(sum)}$	Low peak output current	Sum of $I_{OL(peak)}$ at P0_0 to P0_7, P1_0 to P1_7, P2_0 to P2_7, P8_6, P8_7, P9_0 to P9_7, P10_0 to P10_7, P11_0 to P11_7, P14_0 to P14_1			80.0	mA
		Sum of $I_{OL(peak)}$ at P3_0 to P3_7, P4_0 to P4_7, P5_0 to P5_7, P6_0 to P6_7, P7_0 to P7_7, P8_0 to P8_5, P12_0 to P12_7, P13_0 to P13_7			80.0	mA
$I_{OL(peak)}$	Low peak output current	P0_0 to P0_7, P1_0 to P1_7, P2_0 to P2_7, P3_0 to P3_7, P4_0 to P4_7, P5_0 to P5_7, P6_0 to P6_7, P7_0 to P7_7, P8_0 to P8_7, P9_0 to P9_7, P10_0 to P10_7, P11_0 to P11_7, P12_0 to P12_7, P13_0 to P13_7, P14_0, P14_1			10.0	mA
$I_{OL(avg)}$	Low average output current ⁽¹⁾	P0_0 to P0_7, P1_0 to P1_7, P2_0 to P2_7, P3_0 to P3_7, P4_0 to P4_7, P5_0 to P5_7, P6_0 to P6_7, P7_0 to P7_7, P8_0 to P8_7, P9_0 to P9_7, P10_0 to P10_7, P11_0 to P11_7, P12_0 to P12_7, P13_0 to P13_7, P14_0, P14_1			5.0	mA
$f_{(XIN)}$	Main clock input oscillation frequency	$V_{CC1} = 2.7$ V to 5.5 V	2		20	MHz
$f_{(XCIN)}$	Sub clock oscillation frequency			32.768	50	kHz
$f_{(PLL)}$	PLL clock oscillation frequency	$V_{CC1} = 2.7$ V to 5.5 V	10		32	MHz
$f_{(BCLK)}$	CPU operation clock		2		32	MHz
$t_{SU(PLL)}$	PLL frequency synthesizer stabilization wait time	$V_{CC1} = 5.0$ V			2	ms
		$V_{CC1} = 3.0$ V			3	ms

Note:

1. The average output current is the mean value within 100 ms.

5.1.5 Flash Memory Electrical Characteristics

Table 5.8 CPU Clock When Operating Flash Memory (f_{BCLK})

$V_{\text{CC1}} = 2.7$ to 5.5 V, $T_{\text{opr}} = -20^{\circ}\text{C}$ to $85^{\circ}\text{C}/-40^{\circ}\text{C}$ to 85°C unless otherwise specified.

Symbol	Parameter	Conditions	Standard			Unit
			Min.	Typ.	Max.	
-	CPU rewrite mode				10 (1)	MHz
$f(\text{SLOW_R})$	Slow read mode				5 (3)	MHz
-	Low current consumption read mode			$f\text{C}(32.768)$	35	kHz
-	Data flash read	$2.7\text{ V} \leq V_{\text{CC1}} \leq 3.0\text{ V}$			16 (2)	MHz
		$3.0\text{ V} < V_{\text{CC1}} \leq 5.5\text{ V}$			20 (2)	MHz

Notes:

- Set the PM17 bit in the PM1 register to 1 (one wait).
- When the frequency is over this value, set the FMR17 bit in the FMR1 register to 0 (one wait) or the PM17 bit in the PM1 register to 1 (one wait).
- Set the PM17 bit in the PM1 register to 1 (one wait). When using 125 kHz on-chip oscillator clock or sub clock as the CPU clock source, a wait is not necessary.

Table 5.9 Flash Memory (Program ROM 1, 2) Electrical Characteristics

$V_{\text{CC1}} = 2.7$ to 5.5 V at $T_{\text{opr}} = 0^{\circ}\text{C}$ to 60°C (option: -40°C to 85°C), unless otherwise specified.

Symbol	Parameter	Conditions	Standard			Unit
			Min.	Typ.	Max.	
-	Program and erase cycles (1), (3), (4)	$V_{\text{CC1}} = 3.3\text{ V}$, $T_{\text{opr}} = 25^{\circ}\text{C}$	1,000 (2)			times
-	2 word program time	$V_{\text{CC1}} = 3.3\text{ V}$, $T_{\text{opr}} = 25^{\circ}\text{C}$		150	4000	μs
-	Lock bit program time	$V_{\text{CC1}} = 3.3\text{ V}$, $T_{\text{opr}} = 25^{\circ}\text{C}$		70	3000	μs
-	Block erase time	$V_{\text{CC1}} = 3.3\text{ V}$, $T_{\text{opr}} = 25^{\circ}\text{C}$		0.2	3.0	s
-	Program, erase voltage		2.7		5.5	V
-	Read voltage	$T_{\text{opr}} = -20^{\circ}\text{C}$ to $85^{\circ}\text{C}/-40^{\circ}\text{C}$ to 85°C	2.7		5.5	V
-	Program, erase temperature		0		60	$^{\circ}\text{C}$
t_{PS}	Flash memory circuit stabilization wait time				50	μs
-	Data hold time (6)	Ambient temperature = 55°C	20			year

Notes:

- Definition of program and erase cycles:
The program and erase cycles refer to the number of per-block erasures. If the program and erase cycles are n ($n = 1,000$), each block can be erased n times. For example, if a block is erased after writing 2 word data 16,384 times, each to a different address, this counts as one program and erase cycles. Data cannot be written to the same address more than once without erasing the block (rewrite prohibited).
- Cycles to guarantee all electrical characteristics after program and erase. (1 to Min. value can be guaranteed).
- In a system that executes multiple programming operations, the actual erasure count can be reduced by writing to sequential addresses in turn so that as much of the block as possible is used up before performing an erase operation. It is advisable to retain data on the erasure cycles of each block and limit the number of erase operations to a certain number.
- If an error occurs during block erase, attempt to execute the clear status register command, then execute the block erase command at least three times until the erase error does not occur.
- Customers desiring program/erase failure rate information should contact a Renesas Electronics sales office.
- The data hold time includes time that the power supply is off or the clock is not supplied.

5.1.7 Oscillator Electrical Characteristics

Table 5.16 40 MHz On-Chip Oscillator Electrical Characteristics (1/2)

R5F36506NFA, R5F36506NFB, R5F36506DFA, R5F36506DFB, R5F3651ENFC, R5F3650ENFA, R5F3650ENFB, R5F3651EDFC, R5F3650EDFA, R5F3650EDFB, R5F3651KNFC, R5F3650KNFA, R5F3650KNFB, R5F3651KDFC, R5F3650KDFB, R5F3650KDFA, R5F3651MNFC, R5F3650MNFA, R5F3650MNFB, R5F3651MDFC, R5F3650MDFA, R5F3650MDFB, R5F3651NNFC, R5F3650NNFA, R5F3650NNFB, R5F3651NDFC, R5F3650NDFA, R5F3650NDFB

$V_{CC1} = 2.7$ to 5.5 V, $T_{opr} = -20^{\circ}\text{C}$ to $85^{\circ}\text{C}/-40^{\circ}\text{C}$ to 85°C , unless otherwise specified.

Symbol	Parameter	Condition	Standard			Unit
			Min.	Typ.	Max.	
f_{OCO40M}	40 MHz on-chip oscillator frequency	Average frequency in a 10 ms period	36	40	44	MHz
$tsu(f_{OCO40M})$	Wait time until 40 MHz on-chip oscillator stabilizes				2	ms

Table 5.17 40 MHz On-Chip Oscillator Electrical Characteristics (2/2)

R5F3651RNFC, R5F3650RNFA, R5F3650RNFB, R5F3651RDFC, R5F3650RDFA, R5F3650RDFB, R5F3651TNFC, R5F3650TNFA, R5F3650TNFB, R5F3651TDFC, R5F3650TDFA, R5F3650TDFB

$V_{CC1} = 2.7$ to 5.5 V, $T_{opr} = -20^{\circ}\text{C}$ to $85^{\circ}\text{C}/-40^{\circ}\text{C}$ to 85°C , unless otherwise specified.

Symbol	Parameter	Condition	Standard			Unit
			Min.	Typ.	Max.	
f_{OCO40M}	40 MHz on-chip oscillator frequency	Average frequency in a 10 ms period $2.7\text{ V} \leq V_{CC1} < 5.5\text{ V}$, $T_{opr} = 25^{\circ}\text{C}$	36	40	44	MHz
		Average frequency in a 10 ms period	1	40	60	MHz
$tsu(f_{OCO40M})$	Wait time until 40 MHz on-chip oscillator stabilizes				2	ms

Table 5.18 125 kHz On-Chip Oscillator Electrical Characteristics

$V_{CC1} = 2.7$ to 5.5 V, $T_{opr} = -20^{\circ}\text{C}$ to $85^{\circ}\text{C}/-40^{\circ}\text{C}$ to 85°C , unless otherwise specified.

Symbol	Parameter	Condition	Standard			Unit
			Min.	Typ.	Max.	
f_{OCO-S}	125 kHz on-chip oscillator frequency	Average frequency in a 10 ms period	100	125	150	kHz
$tsu(f_{OCO-S})$	Wait time until 125 kHz on-chip oscillator stabilizes				20	μs

5.2 Electrical Characteristics ($V_{CC1} = V_{CC2} = 5\text{ V}$)

5.2.1 Electrical Characteristics

$$V_{CC1} = V_{CC2} = 5\text{ V}$$

Table 5.19 Electrical Characteristics (1) (1)

$V_{CC1} = V_{CC2} = 4.2\text{ to }5.5\text{ V}$, $V_{SS} = 0\text{ V}$ at $T_{opr} = -20^{\circ}\text{C to }85^{\circ}\text{C}/-40^{\circ}\text{C to }85^{\circ}\text{C}$, $f_{(BCLK)} = 32\text{ MHz}$ unless otherwise specified.

Symbol	Parameter		Measuring Condition	Standard			Unit
				Min.	Typ.	Max.	
V_{OH}	High output voltage	P6_0 to P6_7, P7_2 to P7_7, P8_0 to P8_4, P8_6, P8_7, P9_0 to P9_7, P10_0 to P10_7, P11_0 to P11_7, P14_0, P14_1	$I_{OH} = -5\text{ mA}$	$V_{CC1} - 2.0$		V_{CC1}	V
		P0_0 to P0_7, P1_0 to P1_7, P2_0 to P2_7, P3_0 to P3_7, P4_0 to P4_7, P5_0 to P5_7, P12_0 to P12_7, P13_0 to P13_7	$I_{OH} = -5\text{ mA}$	$V_{CC2} - 2.0$		V_{CC2}	
V_{OH}	High output voltage	P6_0 to P6_7, P7_2 to P7_7, P8_0 to P8_4, P8_6, P8_7, P9_0 to P9_7, P10_0 to P10_7, P11_0 to P11_7, P14_0, P14_1	$I_{OH} = -200\text{ }\mu\text{A}$	$V_{CC1} - 0.3$		V_{CC1}	V
		P0_0 to P0_7, P1_0 to P1_7, P2_0 to P2_7, P3_0 to P3_7, P4_0 to P4_7, P5_0 to P5_7, P12_0 to P12_7, P13_0 to P13_7	$I_{OH} = -200\text{ }\mu\text{A}$	$V_{CC2} - 0.3$		V_{CC2}	
V_{OH}	High output voltage XOUT	HIGH POWER	$I_{OH} = -1\text{ mA}$	$V_{CC1} - 2.0$		V_{CC1}	V
		LOW POWER	$I_{OH} = -0.5\text{ mA}$	$V_{CC1} - 2.0$		V_{CC1}	
	High output voltage XCOUT	HIGH POWER	With no load applied		2.6		V
		LOW POWER	With no load applied		2.2		
V_{OL}	Low output voltage	P6_0 to P6_7, P7_0 to P7_7, P8_0 to P8_7, P9_0 to P9_7, P10_0 to P10_7, P11_0 to P11_7, P14_0, P14_1	$I_{OL} = 5\text{ mA}$			2.0	V
		P0_0 to P0_7, P1_0 to P1_7, P2_0 to P2_7, P3_0 to P3_7, P4_0 to P4_7, P5_0 to P5_7, P12_0 to P12_7, P13_0 to P13_7	$I_{OL} = 5\text{ mA}$			2.0	
V_{OL}	Low output voltage	P6_0 to P6_7, P7_0 to P7_7, P8_0 to P8_7, P9_0 to P9_7, P10_0 to P10_7, P11_0 to P11_7, P14_0, P14_1	$I_{OL} = 200\text{ }\mu\text{A}$			0.45	V
		P0_0 to P0_7, P1_0 to P1_7, P2_0 to P2_7, P3_0 to P3_7, P4_0 to P4_7, P5_0 to P5_7, P12_0 to P12_7, P13_0 to P13_7	$I_{OL} = 200\text{ }\mu\text{A}$			0.45	
V_{OL}	Low output voltage XOUT	HIGH POWER	$I_{OL} = 1\text{ mA}$			2.0	V
		LOW POWER	$I_{OL} = 0.5\text{ mA}$			2.0	
	Low output voltage XCOUT	HIGH POWER	With no load applied		0		V
		LOW POWER	With no load applied		0		

Note:

1. When $V_{CC1} \neq V_{CC2}$, refer to 5 V or 3 V standard depending on the voltage.

$$V_{CC1} = V_{CC2} = 5 \text{ V}$$

Table 5.23 Electrical Characteristics (5)

R5F3651RNFC, R5F3650RNFA, R5F3650RNFB, R5F3651RDFC, R5F3650RDFA, R5F3650RDFB, R5F3651TNFC, R5F3650TNFA, R5F3650TNFB, R5F3651TDFC, R5F3650TDFA, R5F3650TDFB

$V_{CC1} = V_{CC2} = 4.2$ to 5.5 V , $V_{SS} = 0 \text{ V}$ at $T_{opr} = -20$ to $85^\circ\text{C}/-40$ to 85°C , $f_{(BCLK)} = 32 \text{ MHz}$ unless otherwise specified.

Symbol	Parameter	Measuring Condition	Standard			Unit
			Min.	Typ.	Max.	
R_{FXCIN}	Feedback resistance XCIN			15		$M\Omega$
I_{CC}	Power supply current In single-chip, mode, the output pin are open and other pins are V_{SS}	High-speed mode	$f_{(BCLK)} = 32 \text{ MHz}$ XIN = 4 MHz (square wave), PLL multiplied by 8 125 kHz on-chip oscillator stopped	32.0		mA
			$f_{(BCLK)} = 32 \text{ MHz}$, A/D conversion XIN = 4 MHz (square wave), PLL multiplied by 8 125 kHz on-chip oscillator stopped	32.7		mA
			$f_{(BCLK)} = 20 \text{ MHz}$ XIN = 20 MHz (square wave) 125 kHz on-chip oscillator stopped	21.0		mA
		40 MHz on-chip oscillator mode	Main clock stopped 40 MHz on-chip oscillator on, divide-by-4 ($f_{(BCLK)} = 10 \text{ MHz}$) 125 kHz on-chip oscillator stopped	23.0		mA
		125 kHz on-chip oscillator mode	Main clock stopped 40 MHz on-chip oscillator stopped 125 kHz on-chip oscillator on, no division FMR22 = 1 (slow read mode)	750.0		μA
		Low-power mode	$f_{(BCLK)} = 32 \text{ kHz}$ In low-power mode FMR22 = FMR23 = 1 on flash memory ⁽¹⁾	250.0		μA
			$f_{(BCLK)} = 32 \text{ kHz}$ In low-power mode on RAM ⁽¹⁾	45.0		μA
		Wait mode	Main clock stopped 40 MHz on-chip oscillator stopped 125 kHz on-chip oscillator on Peripheral clock operating $T_{opr} = 25^\circ\text{C}$	21.0		μA
			$f_{(BCLK)} = 32 \text{ kHz}$ (oscillation capacity High) 40 MHz on-chip oscillator stopped 125 kHz on-chip oscillator stopped Peripheral clock operating $T_{opr} = 25^\circ\text{C}$	11.0		μA
			$f_{(BCLK)} = 32 \text{ kHz}$ (oscillation capacity Low) 40 MHz on-chip oscillator stopped 125 kHz on-chip oscillator stopped Peripheral clock operating $T_{opr} = 25^\circ\text{C}$	6.0		μA
		Stop mode	Main clock stopped 40 MHz on-chip oscillator stopped 125 kHz on-chip oscillator stopped Peripheral clock stopped $T_{opr} = 25^\circ\text{C}$	1.7		μA
		During flash memory program	$f_{(BCLK)} = 10 \text{ MHz}$, PM17 = 1 (one wait) $V_{CC1} = 5.0 \text{ V}$	20.0		mA
		During flash memory erase	$f_{(BCLK)} = 10 \text{ MHz}$, PM17 = 1 (one wait) $V_{CC1} = 5.0 \text{ V}$	30.0		mA

Note:

- This indicates the memory in which the program to be executed exists.

$$V_{CC1} = V_{CC2} = 5 \text{ V}$$

5.2.2 Timing Requirements (Peripheral Functions and Others)

($V_{CC1} = V_{CC2} = 5 \text{ V}$, $V_{SS} = 0 \text{ V}$, at $T_{opr} = -20^{\circ}\text{C}$ to 85°C / -40°C to 85°C unless otherwise specified)

5.2.2.1 Reset Input ($\overline{\text{RESET}}$ Input)

Table 5.24 Reset Input ($\overline{\text{RESET}}$ Input)

Symbol	Parameter	Standard		Unit
		Min.	Max.	
$t_{w(RSTL)}$	$\overline{\text{RESET}}$ input low pulse width	10		μs

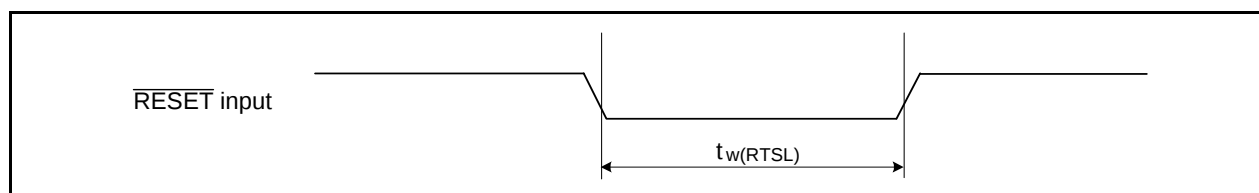


Figure 5.5 Reset Input ($\overline{\text{RESET}}$ Input)

5.2.2.2 External Clock Input

Table 5.25 External Clock Input (XIN Input) (1)

Symbol	Parameter	Standard		Unit
		Min.	Max.	
t_c	External clock input cycle time	50		ns
$t_{w(H)}$	External clock input high pulse width	20		ns
$t_{w(L)}$	External clock input low pulse width	20		ns
t_r	External clock rise time		9	ns
t_f	External clock fall time		9	ns

Note:

- The condition is $V_{CC1} = V_{CC2} = 3.0$ to 5.0 V .

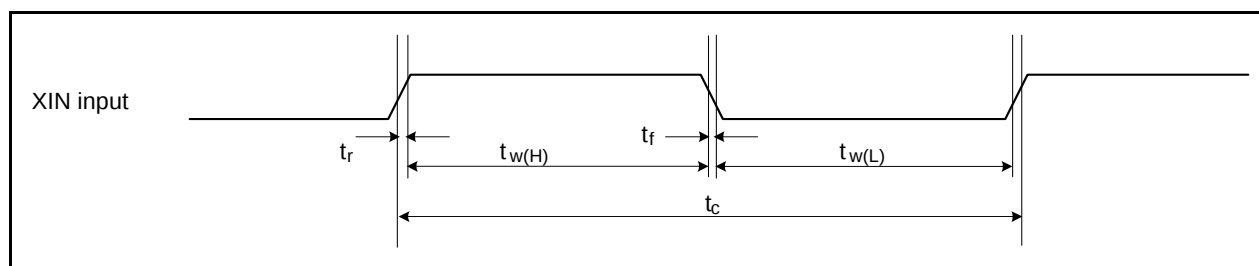


Figure 5.6 External Clock Input (XIN Input)

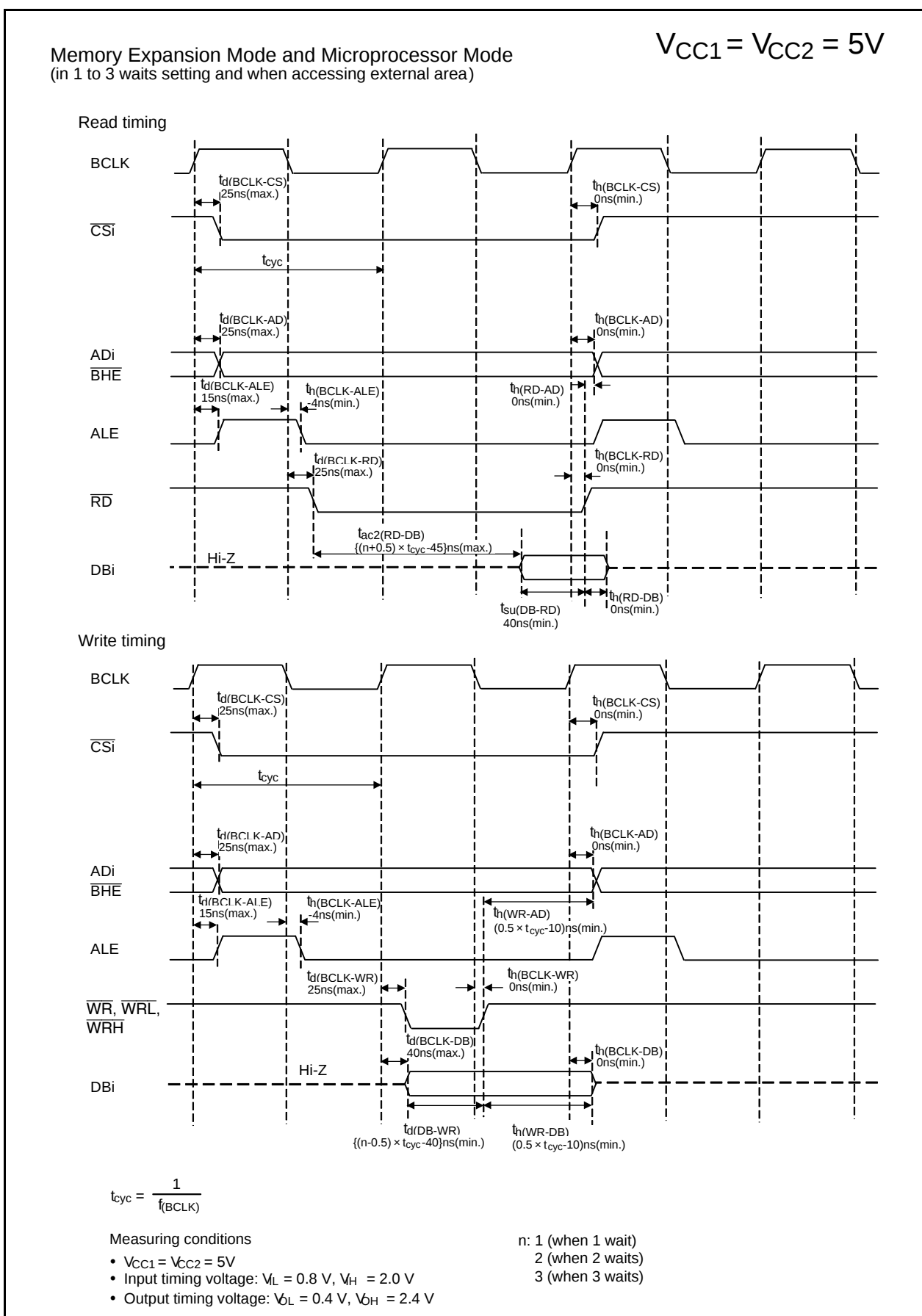


Figure 5.16 Timing Diagram

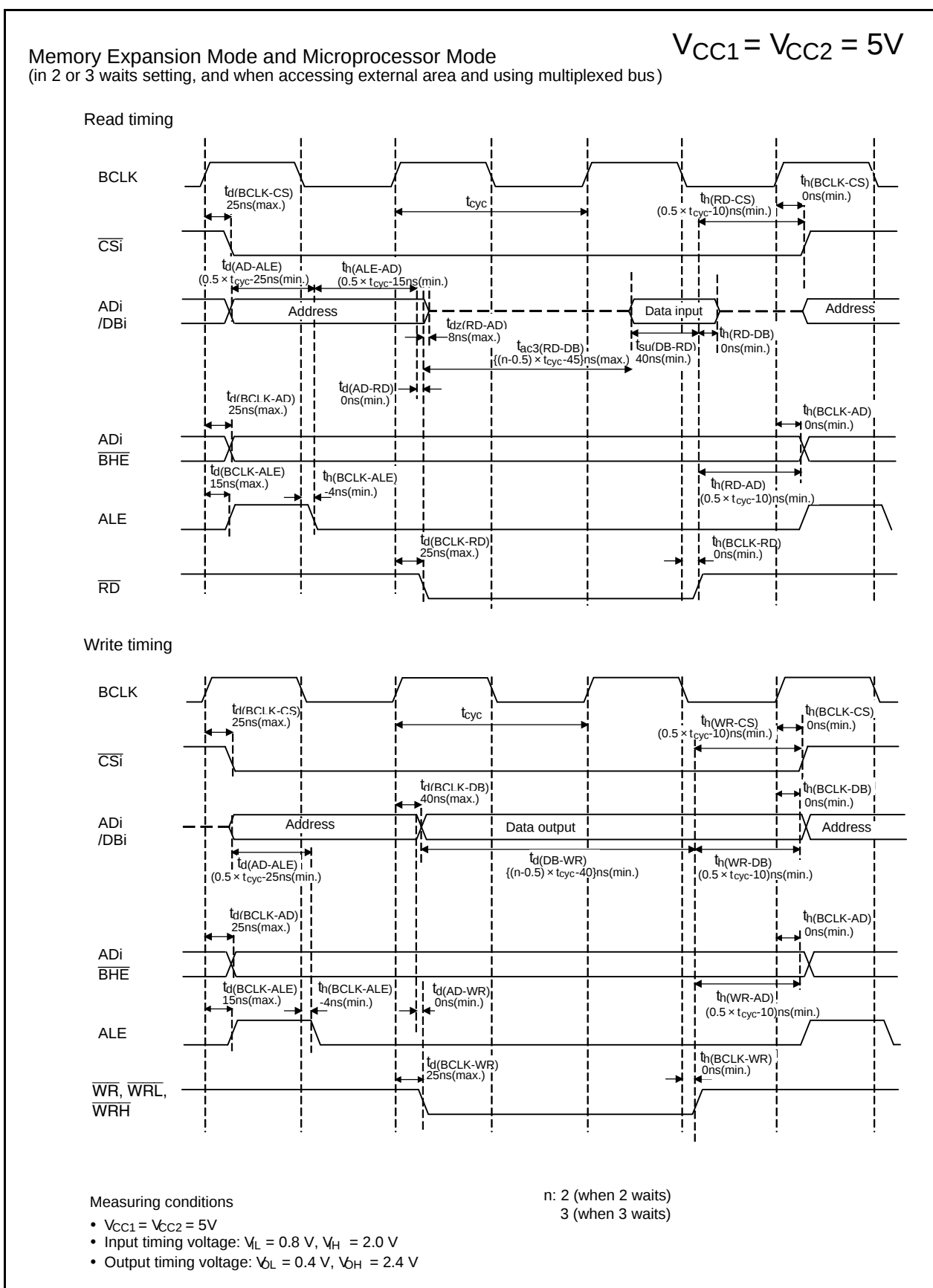


Figure 5.17 Timing Diagram

$$V_{CC1} = V_{CC2} = 5 \text{ V}$$

Switching Characteristics

($V_{CC1} = V_{CC2} = 5 \text{ V}$, $V_{SS} = 0 \text{ V}$, at $T_{opr} = -20^\circ\text{C}$ to $85^\circ\text{C}/-40^\circ\text{C}$ to 85°C unless otherwise specified)

5.2.4.5 In Wait State Setting $2\phi + 3\phi$, $2\phi + 4\phi$, $3\phi + 4\phi$, and $4\phi + 5\phi$, and When Inserting 1 to 3 Recovery Cycles and Accessing External Area

Table 5.42 Memory Expansion and Microprocessor Modes (in Wait State Setting $2\phi + 3\phi$, $2\phi + 4\phi$, $3\phi + 4\phi$, and $4\phi + 5\phi$, and When Inserting 1 to 3 Recovery Cycles and Accessing External Area)

Symbol	Parameter	Measuring Condition	Standard		Unit
			Min.	Max.	
$t_{d(BCLK-AD)}$	Address output delay time	See Figure 5.14		25	ns
$t_{h(BCLK-AD)}$	Address output hold time (in relation to BCLK)		0		ns
$t_{h(RD-AD)}$	Address output hold time (in relation to RD)		(Note 4)		ns
$t_{h(WR-AD)}$	Address output hold time (in relation to WR)		(Note 2)		ns
$t_{d(BCLK-CS)}$	Chip select output delay time			25	ns
$t_{h(BCLK-CS)}$	Chip select output hold time (in relation to BCLK)		0		ns
$t_{d(BCLK-ALE)}$	ALE signal output delay time			15	ns
$t_{h(BCLK-ALE)}$	ALE signal output hold time		-4		ns
$t_{d(BCLK-RD)}$	RD signal output delay time			25	ns
$t_{h(BCLK-RD)}$	RD signal output hold time		0		ns
$t_{d(BCLK-WR)}$	WR signal output delay time			25	ns
$t_{h(BCLK-WR)}$	WR signal output hold time		0		ns
$t_{d(BCLK-DB)}$	Data output delay time (in relation to BCLK)			40	ns
$t_{h(BCLK-DB)}$	Data output hold time (in relation to BCLK) ⁽³⁾		0		ns
$t_{d(DB-WR)}$	Data output delay time (in relation to WR)		(Note 1)		ns
$t_{h(WR-DB)}$	Data output hold time (in relation to WR) ⁽³⁾		(Note 2)		ns

Notes:

1. Calculated according to the BCLK frequency as follows:

$$\frac{n \times 10^9}{f_{(BCLK)}} - 40[ns] \quad n \text{ is 3 for } 2\phi + 3\phi, 4 \text{ for } 2\phi + 4\phi, 4 \text{ for } 3\phi + 4\phi, \text{ and } 5 \text{ for } 4\phi + 5\phi.$$

2. Calculated according to the BCLK frequency as follows:

$$\frac{m \times 10^9}{f_{(BCLK)}} - 10[ns] \quad m \text{ is 1 when 1 recovery cycle is inserted, 2 when 2 recovery cycles are inserted, and 3 when 3 recovery cycles are inserted.}$$

3. This standard value shows the timing when the output is off, and does not show hold time of data bus.

Hold time of data bus varies with capacitor volume and pull-up (pull-down) resistance value.

Hold time of data bus is expressed in

$$t = -CR \times \ln(1 - V_{OL}/V_{CC2})$$

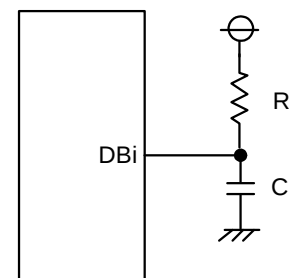
by a circuit of the right figure.

For example, when $V_{OL} = 0.2V_{CC2}$, $C = 30 \text{ pF}$, $R = 1 \text{ k}\Omega$, hold time of output low level is

$$t = -30 \text{ pF} \times 1 \text{ k}\Omega \times \ln(1 - 0.2V_{CC2}/V_{CC2}) = 6.7 \text{ ns.}$$

4. Calculated according to the BCLK frequency as follows:

$$\frac{m \times 10^9}{f_{(BCLK)}} + 0[ns] \quad m \text{ is 1 when 1 recovery cycle is inserted, 2 when 2 recovery cycles are inserted, and 3 when 3 recovery cycles are inserted.}$$



$$V_{CC1} = V_{CC2} = 3\text{ V}$$

Timing Requirements

($V_{CC1} = V_{CC2} = 3\text{ V}$, $V_{SS} = 0\text{ V}$, at $T_{opr} = -20^{\circ}\text{C}$ to $85^{\circ}\text{C}/-40^{\circ}\text{C}$ to 85°C unless otherwise specified)

5.3.2.3 Timer A Input**Table 5.49 Timer A Input (Counter Input in Event Counter Mode)**

Symbol	Parameter	Standard		Unit
		Min.	Max.	
$t_{c(TA)}$	TAiIN input cycle time	150		ns
$t_{w(TAH)}$	TAiIN input high pulse width	60		ns
$t_{w(TAL)}$	TAiIN input low pulse width	60		ns

Table 5.50 Timer A Input (Gating Input in Timer Mode)

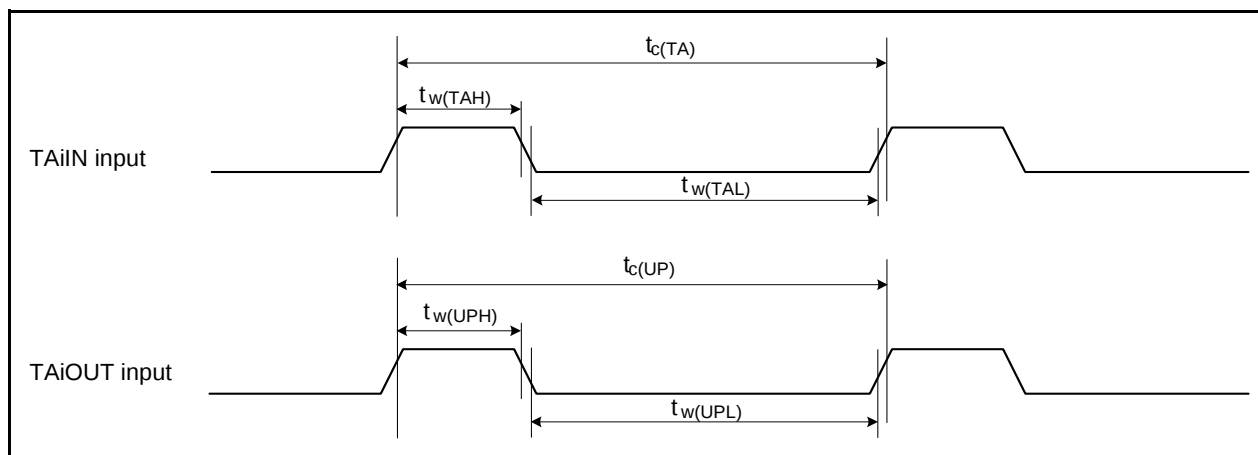
Symbol	Parameter	Standard		Unit
		Min.	Max.	
$t_{c(TA)}$	TAiIN input cycle time	600		ns
$t_{w(TAH)}$	TAiIN input high pulse width	300		ns
$t_{w(TAL)}$	TAiIN input low pulse width	300		ns

Table 5.51 Timer A Input (External Trigger Input in One-Shot Timer Mode)

Symbol	Parameter	Standard		Unit
		Min.	Max.	
$t_{c(TA)}$	TAiIN input cycle time	300		ns
$t_{w(TAH)}$	TAiIN input high pulse width	150		ns
$t_{w(TAL)}$	TAiIN input low pulse width	150		ns

Table 5.52 Timer A Input (External Trigger Input in Pulse Width Modulation Mode and Programmable Output Mode)

Symbol	Parameter	Standard		Unit
		Min.	Max.	
$t_{w(TAH)}$	TAiIN input high pulse width	150		ns
$t_{w(TAL)}$	TAiIN input low pulse width	150		ns

**Figure 5.22 Timer A Input**

$$V_{CC1} = V_{CC2} = 3\text{ V}$$

Timing Requirements

($V_{CC1} = V_{CC2} = 3\text{ V}$, $V_{SS} = 0\text{ V}$, at $T_{opr} = -20^{\circ}\text{C}$ to $85^{\circ}\text{C}/-40^{\circ}\text{C}$ to 85°C unless otherwise specified)

5.3.2.5 Serial Interface

Table 5.57 Serial Interface

Symbol	Parameter	Standard		Unit
		Min.	Max.	
$t_{c(CK)}$	CLKi input cycle time	300		ns
$t_{w(CKH)}$	CLKi input high pulse width	150		ns
$t_{w(CKL)}$	CLKi input low pulse width	150		ns
$t_{d(C-Q)}$	TXDi output delay time		160	ns
$t_{h(C-Q)}$	TXDi hold time	0		ns
$t_{su(D-C)}$	RXDi input setup time	100		ns
$t_{h(C-D)}$	RXDi input hold time	90		ns

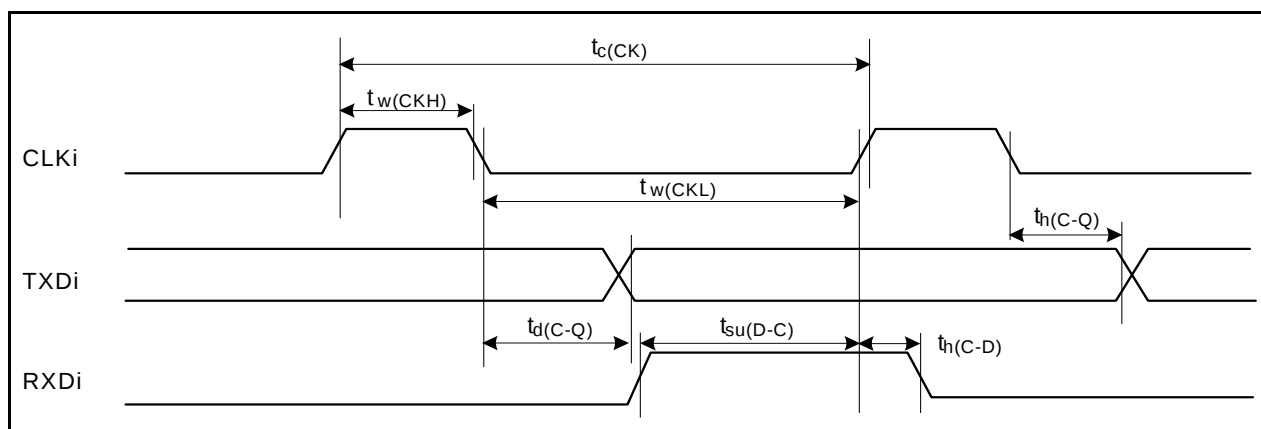


Figure 5.25 Serial Interface

5.3.2.6 External Interrupt $\overline{INTi}$ Input

Table 5.58 External Interrupt $\overline{INTi}$ Input

Symbol	Parameter	Standard		Unit
		Min.	Max.	
$t_{w(INH)}$	$\overline{INTi}$ input high pulse width	380		ns
$t_{w(INL)}$	$\overline{INTi}$ input low pulse width	380		ns

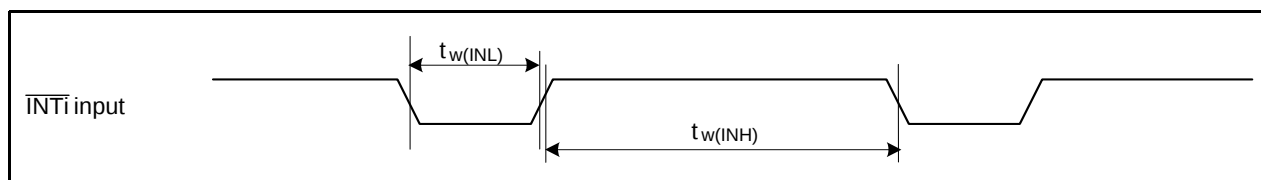


Figure 5.26 External Interrupt $\overline{INTi}$ Input

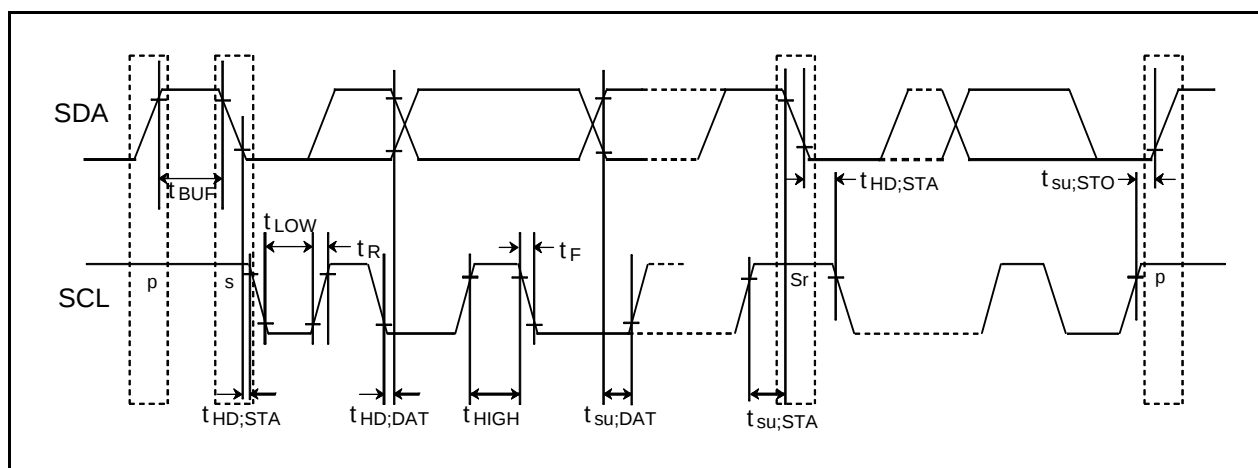
$$V_{CC1} = V_{CC2} = 3\text{ V}$$

Timing Requirements

($V_{CC1} = V_{CC2} = 3\text{ V}$, $V_{SS} = 0\text{ V}$, at $T_{opr} = -20^{\circ}\text{C}$ to $85^{\circ}\text{C}/-40^{\circ}\text{C}$ to 85°C unless otherwise specified)

5.3.2.7 Multi-master I²C-bus**Table 5.59 Multi-master I²C-bus**

Symbol	Parameter	Standard Clock Mode		Fast-mode		Unit
		Min.	Max.	Min.	Max.	
t_{BUF}	Bus free time	4.7		1.3		μs
$t_{HD;STA}$	Hold time in start condition	4.0		0.6		μs
t_{LOW}	Hold time in SCL clock 0 status	4.7		1.3		μs
t_R	SCL, SDA signals' rising time		1000	$20 + 0.1 C_b$	300	ns
$t_{HD;DAT}$	Data hold time	0		0	0.9	μs
t_{HIGH}	Hold time in SCL clock 1 status	4.0		0.6		μs
t_F	SCL, SDA signals' falling time		300	$20 + 0.1 C_b$	300	ns
$t_{su;DAT}$	Data setup time	250		100		ns
$t_{su;STA}$	Setup time in restart condition	4.7		0.6		μs
$t_{su;STO}$	Stop condition setup time	4.0		0.6		μs

**Figure 5.27 Multi-master I²C-bus**

$$V_{CC1} = V_{CC2} = 3 \text{ V}$$

Switching Characteristics

($V_{CC1} = V_{CC2} = 3 \text{ V}$, $V_{SS} = 0 \text{ V}$, at $T_{opr} = -20^{\circ}\text{C}$ to 85°C / -40°C to 85°C unless otherwise specified)

5.3.4.3 In 2 or 3 Waits Setting, and When Accessing External Area and Using Multiplexed Bus

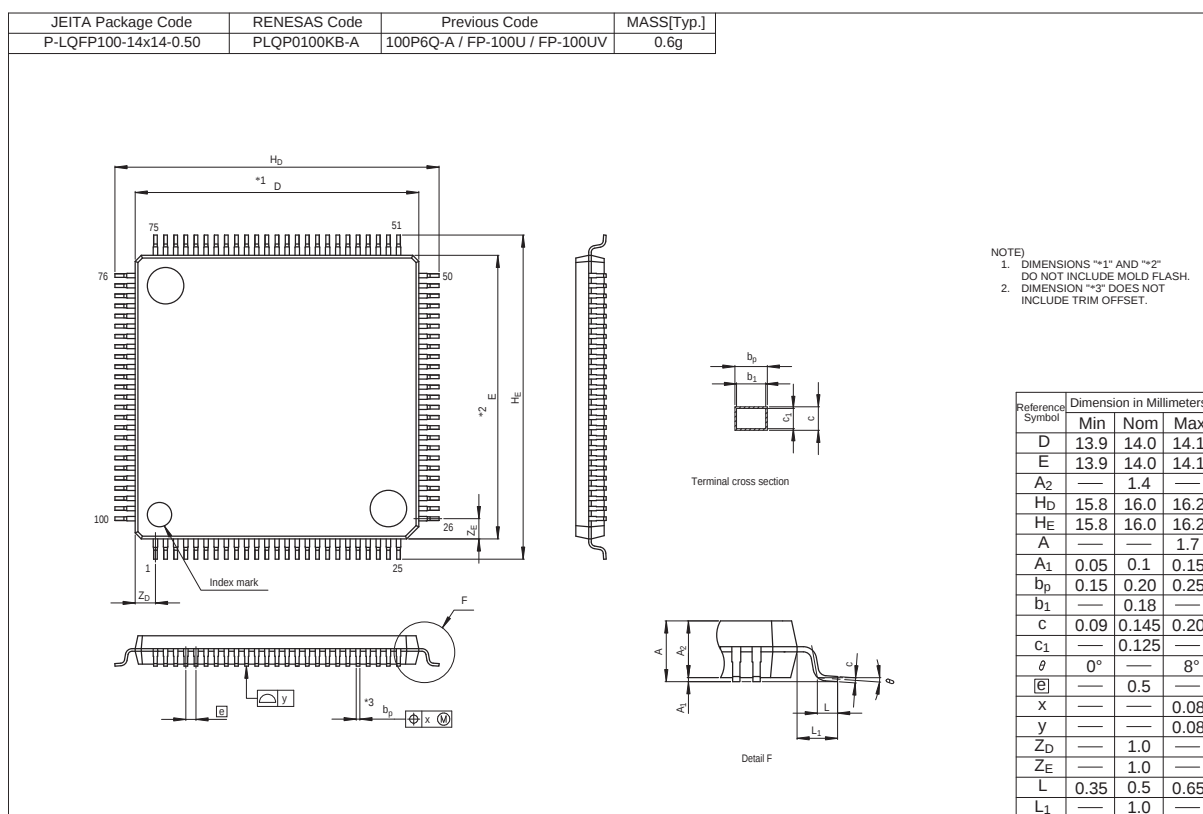
Table 5.63 Memory Expansion Mode and Microprocessor Mode (in 2 or 3 Waits Setting, and When Accessing External Area and Using Multiplexed Bus) ⁽⁵⁾

Symbol	Parameter	Measuring Condition	Standard		Unit
			Min.	Max.	
$t_{d(BCLK-AD)}$	Address output delay time	See Figure 5.29		50	ns
$t_{h(BCLK-AD)}$	Address output hold time (in relation to BCLK)		0		ns
$t_{h(RD-AD)}$	Address output hold time (in relation to RD)		(Note 1)		ns
$t_{h(WR-AD)}$	Address output hold time (in relation to WR)		(Note 1)		ns
$t_{d(BCLK-CS)}$	Chip select output delay time			50	ns
$t_{h(BCLK-CS)}$	Chip select output hold time (in relation to BCLK)		0		ns
$t_{h(RD-CS)}$	Chip select output hold time (in relation to RD)		(Note 1)		ns
$t_{h(WR-CS)}$	Chip select output hold time (in relation to WR)		(Note 1)		ns
$t_{d(BCLK-RD)}$	RD signal output delay time			40	ns
$t_{h(BCLK-RD)}$	RD signal output hold time		0		ns
$t_{d(BCLK-WR)}$	WR signal output delay time			40	ns
$t_{h(BCLK-WR)}$	WR signal output hold time		0		ns
$t_{d(BCLK-DB)}$	Data output delay time (in relation to BCLK)			50	ns
$t_{h(BCLK-DB)}$	Data output hold time (in relation to BCLK)		0		ns
$t_{d(DB-WR)}$	Data output delay time (in relation to WR)		(Note 2)		ns
$t_{h(WR-DB)}$	Data output hold time (in relation to WR)		(Note 1)		ns
$t_{d(BCLK-ALE)}$	ALE signal output delay time (in relation to BCLK)			25	ns
$t_{h(BCLK-ALE)}$	ALE signal output hold time (in relation to BCLK)		-4		ns
$t_{d(AD-ALE)}$	ALE signal output delay time (in relation to Address)		(Note 3)		ns
$t_{h(AD-ALE)}$	ALE signal output hold time (in relation to Address)		(Note 4)		ns
$t_{d(AD-RD)}$	RD signal output delay from the end of address		0		ns
$t_{d(AD-WR)}$	WR signal output delay from the end of address		0		ns
$t_{dz(RD-AD)}$	Address output floating start time			8	ns

Notes:

1. Calculated according to the BCLK frequency as follows: $\frac{0.5 \times 10^9}{f_{(BCLK)}} - 10[\text{ns}]$
2. Calculated according to the BCLK frequency as follows:

$$\frac{(n - 0.5) \times 10^9}{f_{(BCLK)}} - 50[\text{ns}] \quad n \text{ is 2 for 2 waits setting, 3 for 3 waits setting.}$$
3. Calculated according to the BCLK frequency as follows: $\frac{0.5 \times 10^9}{f_{(BCLK)}} - 40[\text{ns}]$
4. Calculated according to the BCLK frequency as follows: $\frac{0.5 \times 10^9}{f_{(BCLK)}} - 15[\text{ns}]$
5. When using multiplexed bus, set $f_{(BCLK)}$ 12.5 MHz or less.



REVISION HISTORY	M16C/65 Group Datasheet
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Rev.	Date	Description	
		Page	Summary
2.00	Dec 10, 2010	Special Function Registers (SFRs)	
		31	Table 4.1 SFR Information (1): • Deleted "the VCR1 register, the VCR2 register" from note 2. • Deleted notes 5 to 6 and added note 5.
		32	Table 4.2 SFR Information (2): Deleted notes 2 to 7 and added note 2.
		49	4.2.1 Register Settings: Added the description regarding read-modify-write instructions.
		50	Table 4.20 Read-Modify-Write Instructions: Added.
		Electrical Characteristics	
		51	Table 5.1 Absolute Maximum Ratings: Added a row for the data area value to T_{opr} (Flash program erase).
		52	Table 5.2 Recommended Operating Conditions (1/3): Added rows for the CEC value to V_{CC1} , V_{CC2} , V_{IH} , and V_{IL} .
		57	Table 5.9 Flash Memory (Program ROM 1, 2) Electrical Characteristics: Added a condition to the Read voltage row.
		60	Table 5.14 Power-On Reset Circuit: • Added the $t_{w(por)}$ row. • Added the last line in note 1.
		60	Figure 5.3 Power-On Reset Circuit Electrical Characteristics: Deleted note 2.
		64	Table 5.20 Electrical Characteristics (2): Added "ZP, IDU, IDV, IDW" to the $V_{T+} - V_{T-}$ row.
		65	Table 5.21 Electrical Characteristics (3): Moved R5F3651ENFC and R5F3651EDFC to Table 5.22 Electrical Characteristics (4).
		73, 96	5.2.2.7 and 5.3.2.7 Multi-master I ² C-bus: Added.
		74 to 81, 97 to 104	Table 5.37 to Table 5.42 and Table 5.60 to Table 5.65 Memory Expansion Mode and Microprocessor Mode: Deleted the following: • $\overline{HOLD}$ input setup time • $\overline{HOLD}$ input hold time • $\overline{HLDA}$ output delay time
		74	Table 5.37 Memory Expansion Mode and Microprocessor Mode: Changed $\overline{RDY}$ input setup time from 30.
		75, 98	Figure 5.13 and Figure 5.28 Timing Diagram: Deleted lower figure (Common to wait state and no wait state settings).
		86, 109	Figure 5.19 and Figure 5.34 Timing Diagram: Changed the width of $t_h(RD-AD)$.
		87	Table 5.43 Electrical Characteristics (1): • Added rows for the CEC value to V_{OL} , $V_{T+}-V_{T-}$, and Leakage current in powered-off state. • Added "ZP, IDU, IDV, IDW" to the $V_{T+} - V_{T-}$ row.
		88	Table 5.44 Electrical Characteristics (2): Moved R5F3651ENFC and R5F3651EDFC to Table 5.45 Electrical Characteristics (3).
		88 to 90	Table 5.44 to Table 5.46 Electrical Characteristics (2) to (4): Changed " $V_{CC1} = 5.0\text{ V}$ " to " $V_{CC1} = 3.0\text{ V}$ " in the During flash memory program and During flash memory erase rows.
		97	Table 5.60 Memory Expansion Mode and Microprocessor Mode: Changed $\overline{RDY}$ input setup time from 40.
2.10	Ju. 31, 2012	Electrical Characteristics	
		V_{CC} = 5 V	
		65, 66, 67	Table 5.21 Electrical Characteristics (3), Table 5.22 Electrical Characteristics (4), and Table 5.23 Electrical Characteristics (5): Changed the Measuring Condition column of 40 MHz on-chip oscillator for the 40 MHz on-chip oscillator mode in the I_{CC} .
		V_{CC} = 3 V	
		88, 89, 90	Table 5.44 Electrical Characteristics (2), Table 5.45 Electrical Characteristics (3), and Table 5.46 Electrical Characteristics (4): Changed the Measuring Condition column of 40 MHz on-chip oscillator for the 40 MHz on-chip oscillator mode in the I_{CC} .

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